



Product Summary

V _{(BR)DSS}	R _{DS(ON)} max	I _D max T _A = +25°C
	2Ω @ V _{GS} = 5.0V	500mA
60V	2.5Ω @ V _{GS} = 2.5V	450mA

Description and Applications

This MOSFET has been designed to minimize the on-state resistance $(R_{DS(ON)})$ yet maintain superior switching performance, making it ideal for high efficiency power management applications.

DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Dual N-Channel MOSFET
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Up To 2kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotiveproducts/.

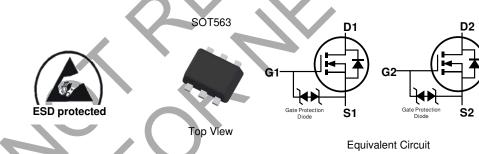
• This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

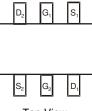
https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: SOT563
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)

Weight: 0.006 grams (Approximate)





Top View Pin out

Ordering Information (Note 4)

Part Number	Package	Packing			
Fait Nulliber	Fackage	Qty.	Carrier		
DMN61D9UV-7	SOT563	3,000	Tape & Reel		
DMN61D9UV-13	SOT563	10,000	Tape & Reel		

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

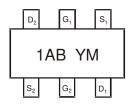
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Notes:



Marking Information



1AB = Product Type Marking Code YM = Date Code Marking Y = Year ex: J = 2022 M = Month ex: 9 = September

ate Code Key												
Year	2015		2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	С		J	K	L	М	Ν	0	Р	R	S	Т
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D
	•	•	•	•	•	-					•	•

Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic				Symbol			Value	Units	
Drain-Source Voltage				VDSS			60	V	
Gate-Source Voltage			7	Vgss			±20	V	
Continuous Drain Current (Note 6) $V_{GS} = 5.0V$	Steady State	T _A = +25°C T _A = +70°C		١D			500 400	mA	
Maximum Continuous Body Diode Forward Current (Note 6)				ls			0.4	А	
Pulsed Drain Current (10µs pulse, duty cycle = 1%)				Ідм	V		1.2	A	

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 5)		PD	520	mW
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	242	°C/W
Total Power Dissipation (Note 6)		PD	800	mW
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R _{0JA}	159	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Notes:

Device mounted on FR-4 PCB, with minimum recommended pad layout.
Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. Copper, single sided.



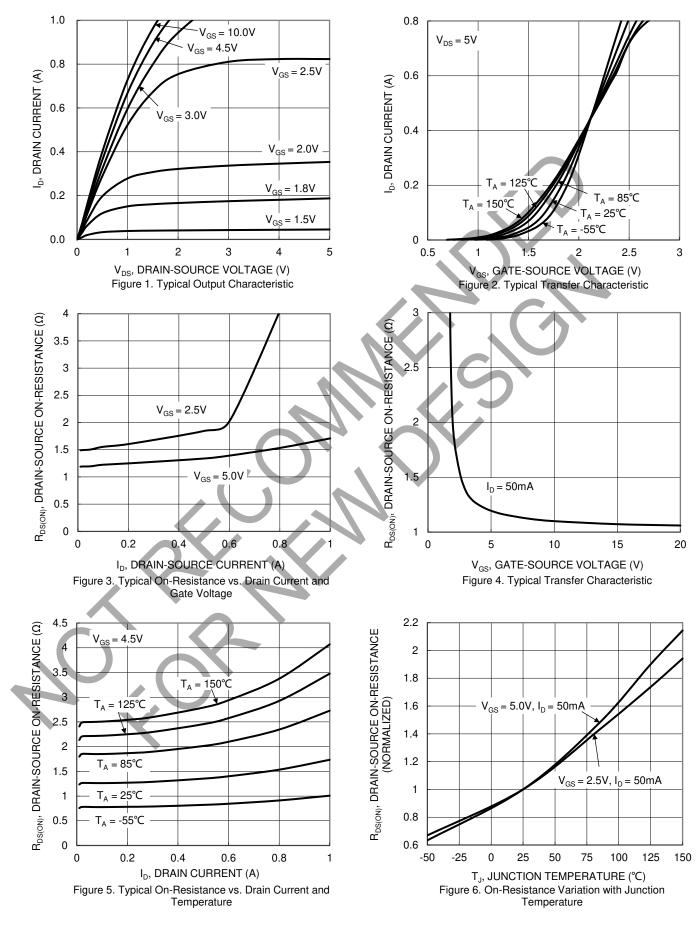
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

		1	1	1		
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)	_					
Drain-Source Breakdown Voltage	BVDSS	60	—	—	V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current	IDSS	—	—	1.0	μA	$V_{DS} = 60V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	—	—	±10	μA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	VGS(TH)	0.5	_	1.0	V	$V_{DS} = 10V, I_D = 250 \mu A$
			1.2	2.0		$V_{GS} = 5.0V, I_D = 0.05A$
Static Drain-Source On-Resistance	RDS(ON)	—	1.6	2.5	Ω	$V_{GS} = 2.5V, I_D = 0.05A$
			2.5	3.5		$V_{GS} = 1.8V, I_D = 0.05A$
Forward Transconductance	Y _{fs}	200	_	—	mS	VDS = 10V, ID = 0.2A
Diode Forward Voltage	V _{SD}	—	0.75	1.4	V	$V_{GS} = 0V, I_{S} = 115mA$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	—	28.5		pF	
Output Capacitance	Coss	—	3.9	l	рF	V _{DS} = 30V, V _{GS} = 0V f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	2.5		рF	1 = 1.0MHZ
Gate Resistance	Rg	_	65	1	Ω	$f = 1MHz$, $V_{GS} = 0V$, $V_{DS} = 0V$
Total Gate Charge	Qg	—	0.4	1	nC	
Gate-Source Charge	Qgs	-	0.1		nC	VGS = 4.5V, VDS = 10V, ID = 250mA
Gate-Drain Charge	Q _{gd}		0.1		nC	
Turn-On Delay Time	td(on)	ł	2.1	<u> </u>	ns	
Turn-On Rise Time	tR	-	1.8	—	ns	$V_{DD} = 30V, V_{GS} = 10V,$
Turn-Off Delay Time	tD(OFF)		14.4	—	ns	$R_G = 25\Omega, I_D = 200 mA$
Turn-Off Fall Time	t⊧		8.4	-	ns	

Notes: 7. Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to product testing.

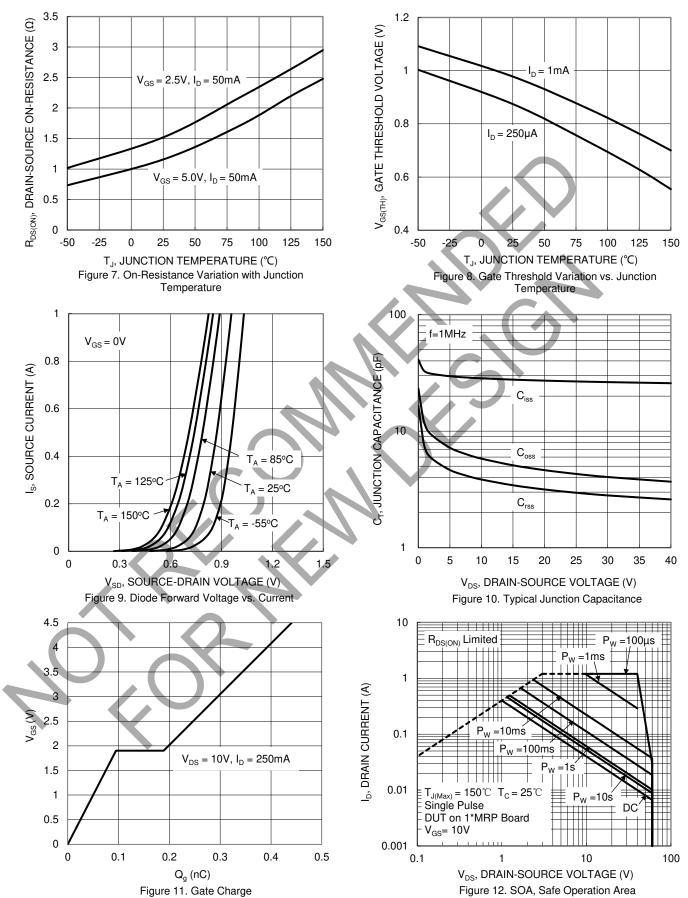


DMN61D9UV

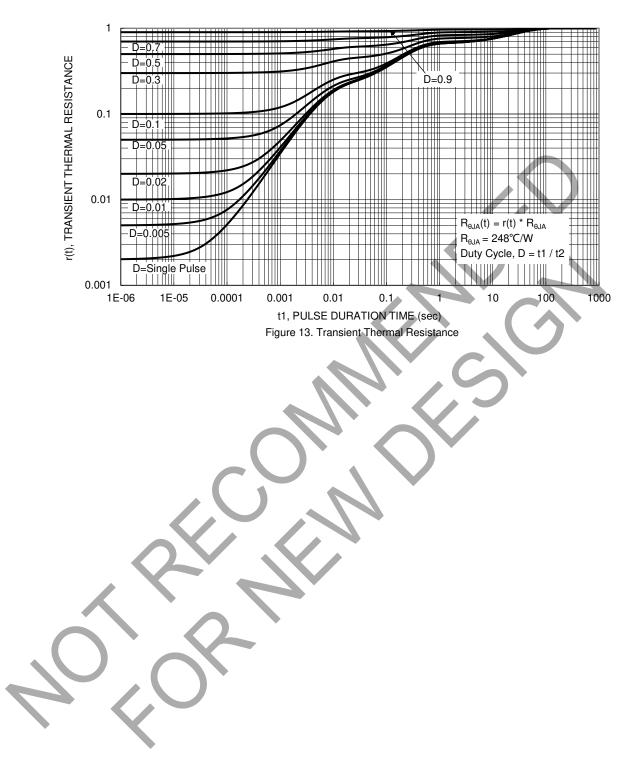




DMN61D9UV



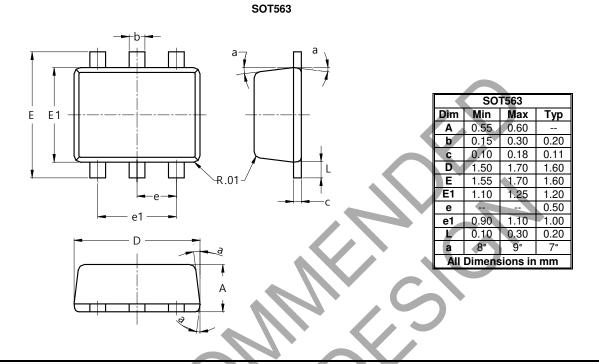






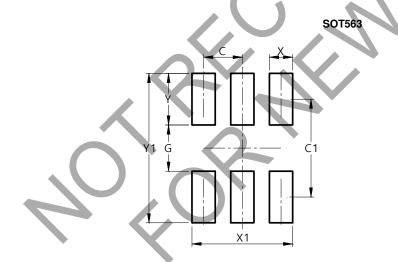
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.500
C1	1.270
G	0.600
Х	0.300
X1	1.300
Y	0.670
Y1	1.940



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